

Supplementary Information

Dual-Phase MoS₂ as a High-Performance Sodium-Ion Battery Anode

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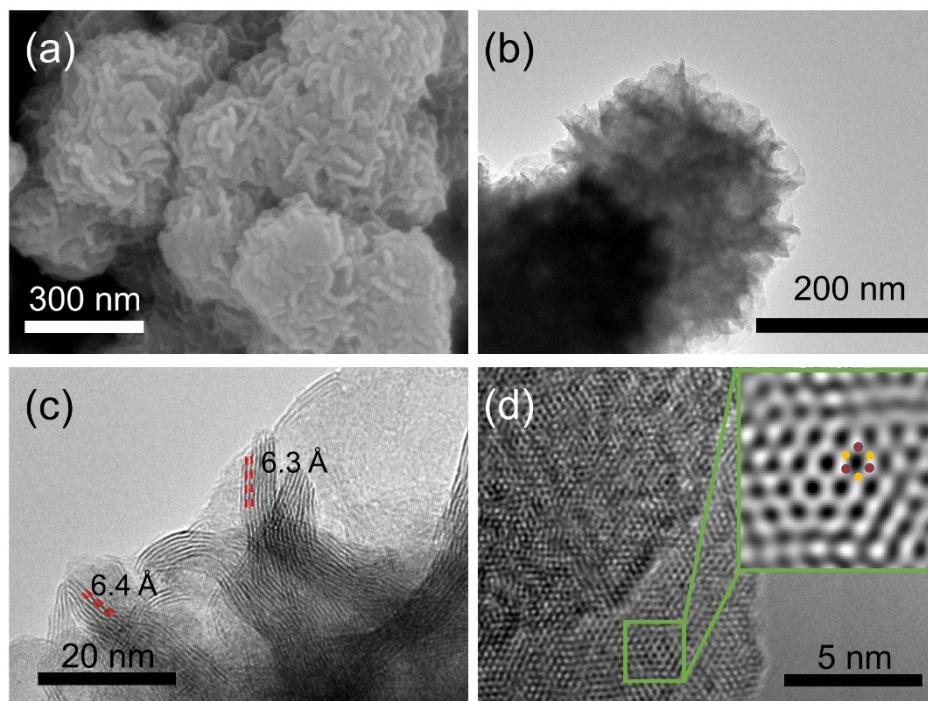


Figure S1. (a) SEM, (b) low-, and (c) high-magnification TEM and (d) HRTEM images of 2H-MoS₂.

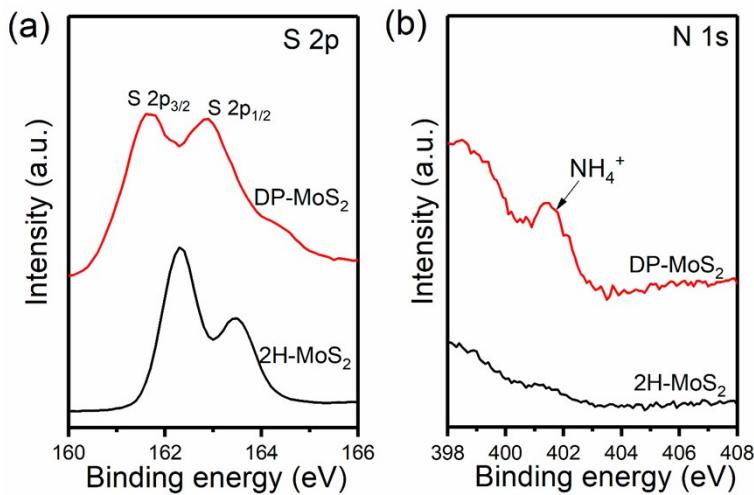


Figure S2. High resolution S 2p (a) and N 1s (b) XPS spectra of DP-MoS₂ and 2H-MoS₂.

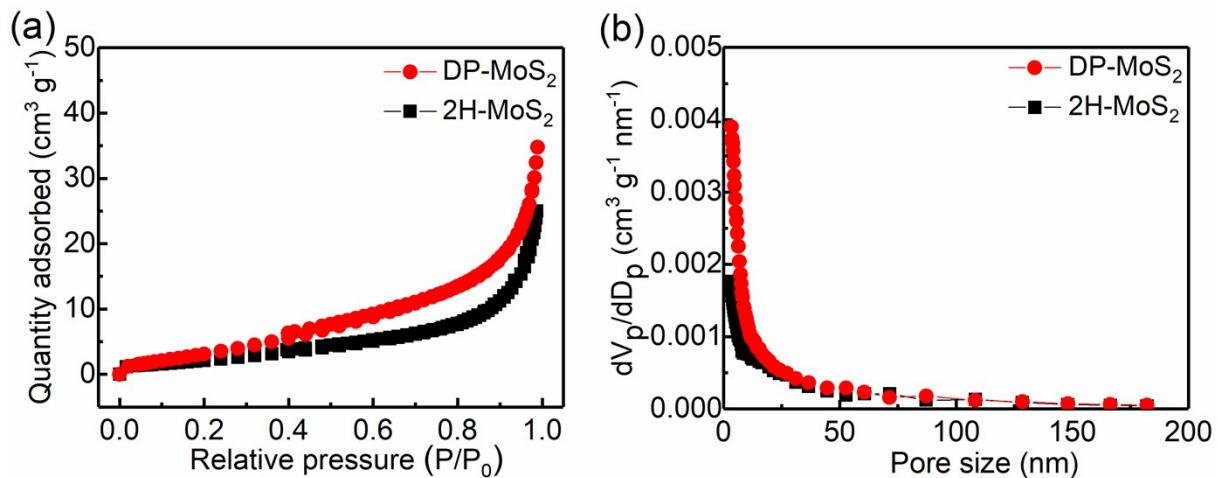


Figure S3. (a) N₂ adsorption/desorption isotherms and (b) pore size distribution curves of DP-MoS₂ and 2H-MoS₂.

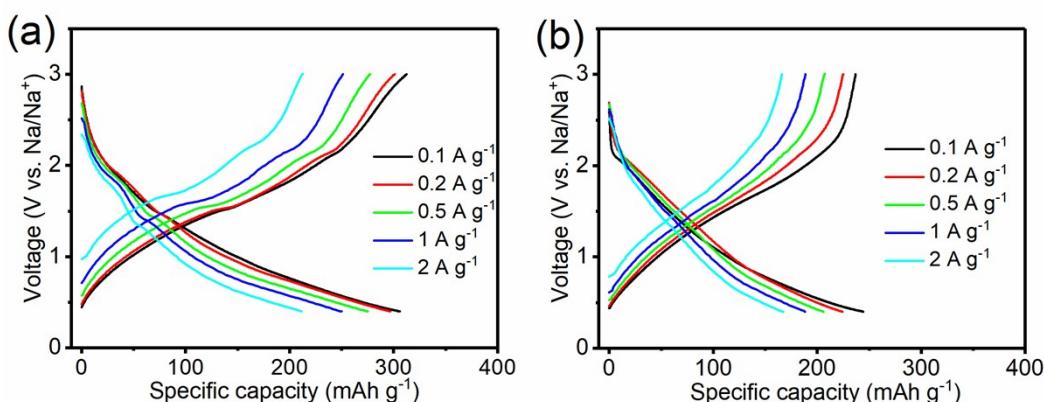


Figure S4. Charge/discharge curves of (a) the DP-MoS₂ and (b) 2H-MoS₂ electrodes at current densities varying from 0.1 A g⁻¹ to 2 A g⁻¹.

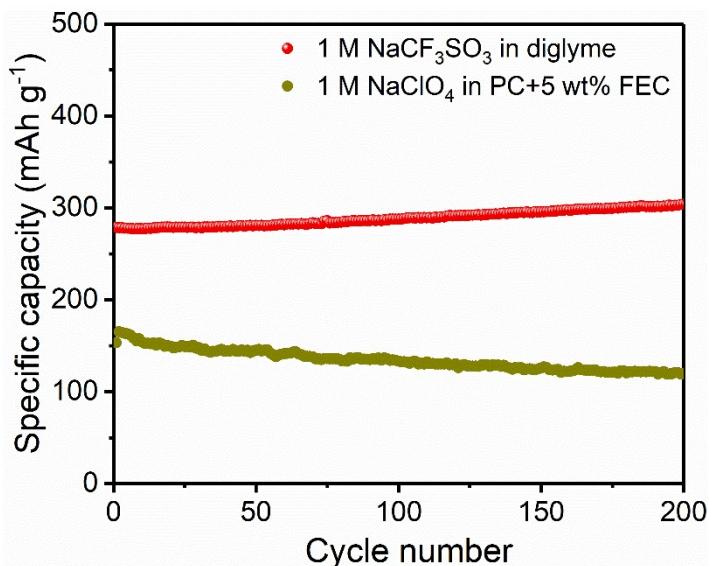


Figure S5. Cyclic performance of the DP-MoS₂ electrode in ether- and ester-based electrolytes.

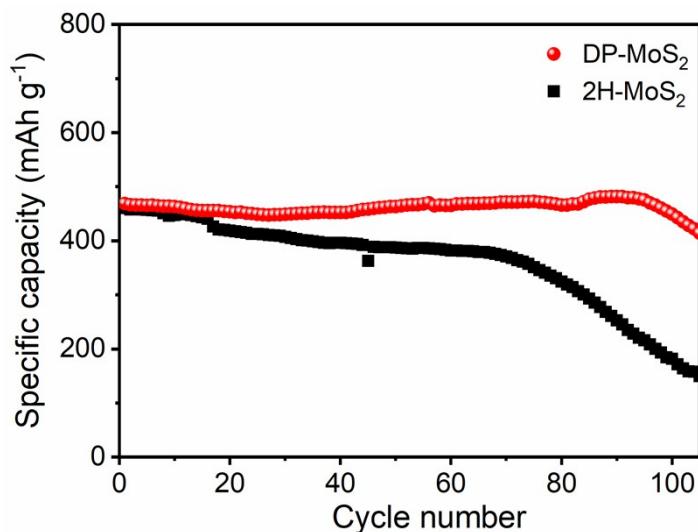


Figure S6. Cyclic performance of the DP-MoS₂ and 2H-MoS₂ electrodes at 0.5 A g⁻¹ in the voltage range from 0.01 to 3 V (vs. Na/Na⁺).

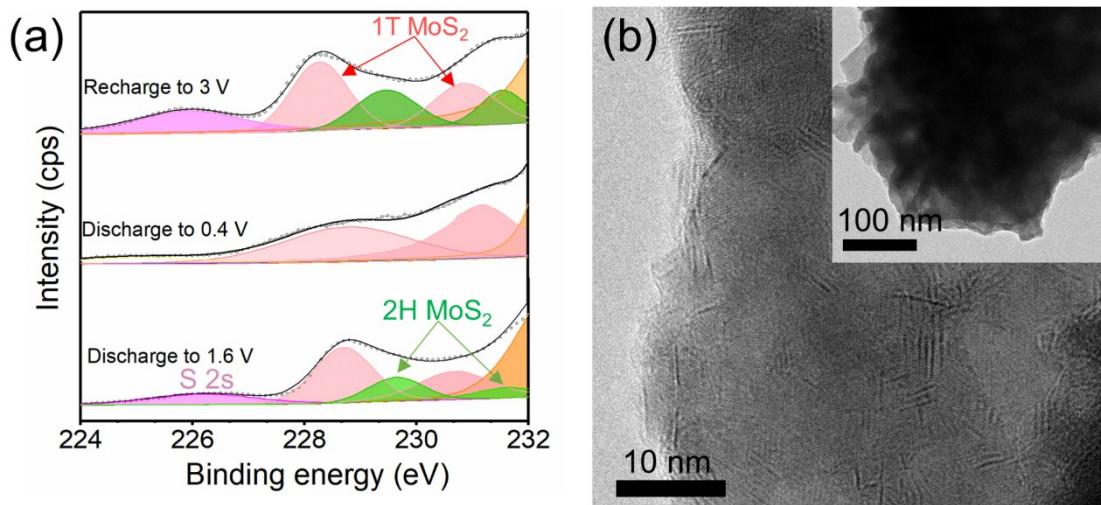


Figure S7. (a) *Ex-situ* XPS of DP-MoS₂ at different potentials; (b) HRTEM images of DP-MoS₂ taken after discharging to 0.4 V in the 100th cycle.

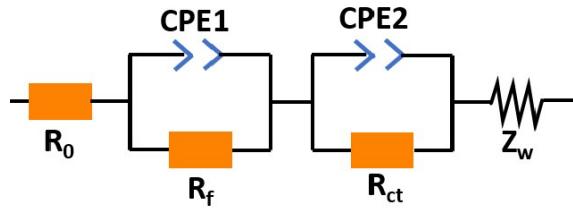


Figure S8. Equivalent circuit used for fitting the EIS data.

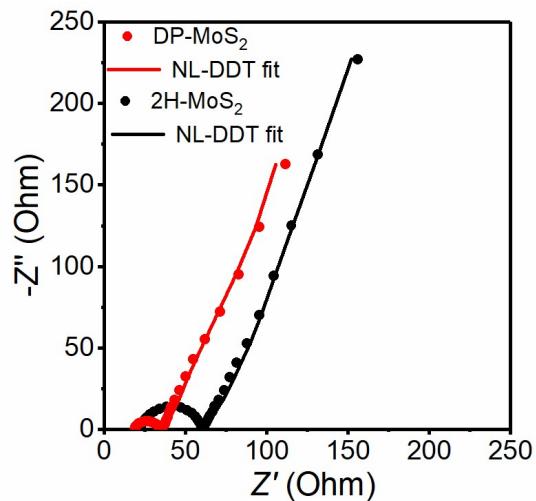


Figure S9. Nyquist plots with NL-DDT fit of Na//DP-MoS₂ and Na//2H-MoS₂ batteries.

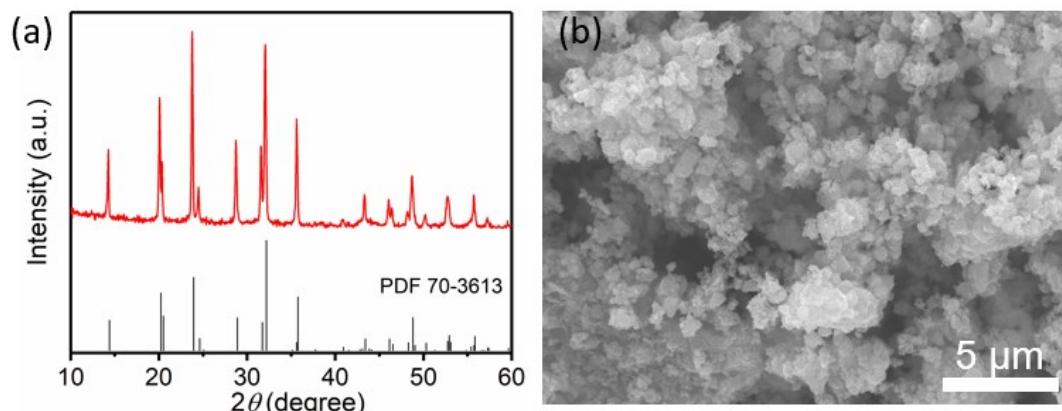


Figure S10. (a) XRD pattern and (b) SEM image of NVP cathode.

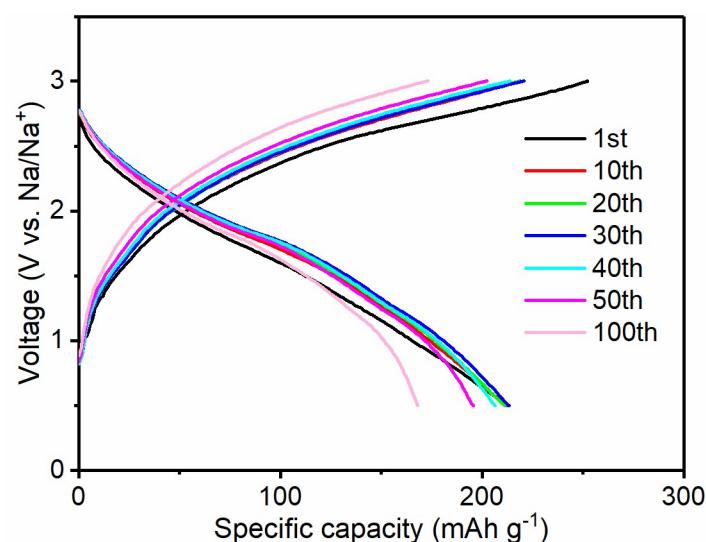


Figure S11. Charge/discharge curves of the DP-MoS₂/NVP full cell at a current density of 0.5 A g⁻¹.

Table S1. Impedance parameters predicted from the Nyquist plots using the equivalent circuit shown in Figure S7.

Electrode	DP-MoS ₂	2H-MoS ₂
R _o (Ω)	18.9	22.3
R _f (Ω)	3.0	5.1
R _{ct} (Ω)	13.8	31.3

Table S2. Comparison of the electrochemical performance of published SIB anode against the current work

Material	Preparation method	Electrochemical performance		Ref.
		Cyclic performance	Rate performance	
DP-MoS ₂	Solvothermal	220 mAh g ⁻¹ at 2A g ⁻¹ after 500 cycles	255 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 220 mAh g ⁻¹ at 2.0 A g ⁻¹	Current work
1T MoS ₂ /GF	Solvothermal	313 mAh g ⁻¹ at 0.05 A g ⁻¹ after 200 cycles	208 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 175 mAh g ⁻¹ at 2.0 A g ⁻¹	S1
1T-MoS ₂	Li ⁺ intercalation assisted exfoliation	324 mAh g ⁻¹ at 1.0 A g ⁻¹ after 200 cycles	301 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 253 mAh g ⁻¹ at 2.0A g ⁻¹	S2
MXene	HF etching	~140 mAh g ⁻¹ at 0.02 A g ⁻¹ after 100 cycles	113 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 90 mAh g ⁻¹ at 2.0 A g ⁻¹	S3
Expanded graphite	Two-step oxidation-reduction	~180 mAh g ⁻¹ at 0.1 A g ⁻¹	184 mAh g ⁻¹ at 0.1 mA g ⁻¹ ; 91 mAh g ⁻¹ at 0.2 mA g ⁻¹	S4
MoS ₂ -PEO composite	Exfoliation-restacking	148 mAh g ⁻¹ at 0.05 A g ⁻¹ after 70 cycles	127 mAh g ⁻¹ at 0.5 A g ⁻¹ ; 112 mAh g ⁻¹ at 1.0A g ⁻¹	S5
MoS ₂ /C	Hydrothermal and calcination	~120 mAh g ⁻¹ at 1.0 A g ⁻¹ after 800 cycles	125 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 100 mAh g ⁻¹ at 2.0 A g ⁻¹	S6
MoS _{2x} Se _x /GF	Hydrothermal and calcination	~165 mAh g ⁻¹ at 0.2 A g ⁻¹ after 500 cycles	180 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 175 mAh g ⁻¹ at 2.0 A g ⁻¹	S7
VO-MoS ₂ /N-RGO	Solvothermal	245 mAh g ⁻¹ at 1.0 A g ⁻¹ after 1300 cycles	248 mAh g ⁻¹ at 1.0 A g ⁻¹ ; 243 mAh g ⁻¹ at 2.0 A g ⁻¹	S8

References

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